# Low-Voltage Single SPDT Analog Switch 

## DESCRIPTION

The DG9411 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed ( $\mathrm{t}_{\mathrm{ON}}: 9 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{OFF}}: 5 \mathrm{~ns}$ ), low on-resistance ( $\mathrm{r}_{\mathrm{DS}(\mathrm{on})}: 7 \Omega$ ) and small physical size (SC70), the DG9411 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG9411 is built on Vishay Siliconix's low voltage JI2 process. An epitaxial layer prevents latchup. Break-before make is guaranteed for DG9411.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

## FEATURES

- Low voltage operation (2.25 V to 5.5 V )
- Low on-resistance - $r_{\text {DS(on): }}: 7 \Omega$
- Fast switching - $\mathrm{t}_{\mathrm{ON}}: 9 \mathrm{~ns}, \mathrm{t}_{\mathrm{OFF}}: 5 \mathrm{~ns}$
- Low charge injection $-\mathrm{Q}_{\mathrm{INJ}}: 5 \mathrm{pC}$
- Low power consumption
- TTL/CMOS compatible
- 6-Pin SC70 package


## BENEFITS

- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space


## APPLICATIONS

- Cellular phones
- Communication systems
- Portable test equipment
- Battery operated systems
- Sample and hold circuits


RoHS* COMPLIANT

## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE |  |  |
| :---: | :---: | :---: |
| Logic | NC | NO |
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic "0" $\leq 0.8 \mathrm{~V}$
Logic "1" $\geq 2.4 \mathrm{~V}$

| ORDERING INFORMATION |  |  |
| :---: | :---: | :---: |
| Temp Range | Package | Part Number |
| -40 to $85^{\circ} \mathrm{C}$ | SC70-6 | DG9411DL-T1 <br> DG9411DL-T1-E3 |

[^0]| ABSOLUTE MAXIMUM RATINGS |  |  |  |
| :---: | :---: | :---: | :---: |
| Parameter |  | Limit | Unit |
| Reference V+ to GND |  | - 0.3 to + 6 | V |
| IN, COM, NC, $\mathrm{NO}^{\text {a }}$ |  | -0.3 to (V++0.3) |  |
| Continuous Current (Any Terminal) |  | $\pm 50$ | mA |
| Peak Current (Pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle) |  | $\pm 200$ |  |
| Storage Temperature |  | - 65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Power Dissipation (Packages) ${ }^{\text {b }}$ | $6-\mathrm{Pin} \mathrm{SC} 70^{\text {c }}$ | 250 | mW |

## Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate $3.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$.

| SPECIFICATIONS $\mathrm{V}+=2.5 \mathrm{~V}$ |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Test Conditions Unless Otherwise Specified$\begin{aligned} & \mathrm{V}+=2.5 \mathrm{~V}, \pm 10 \% \\ & \mathrm{~V}_{\mathrm{IN}}=0.4 \text { or } 2.0 \mathrm{~V}^{\mathrm{e}} \end{aligned}$ | Temp ${ }^{\text {a }}$ | $\begin{gathered} \text { Limits } \\ -40 \text { to } 85^{\circ} \mathrm{C} \end{gathered}$ |  |  | Unit |
|  |  |  |  | Min ${ }^{\text {b }}$ | Typ ${ }^{\text {c }}$ | Max ${ }^{\text {b }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |
| Analog Signal Range ${ }^{\text {d }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{NC}} \\ \mathrm{~V}_{\mathrm{COM}} \end{gathered}$ |  | Full | 0 |  | V+ | V |
| Drain-Source On-Resistance | ${ }^{\text {r DS(on) }}$ | $\mathrm{V}+=2.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=1.0 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=10 \mathrm{~mA}$ | Room Full ${ }^{\text {d }}$ |  | $\begin{aligned} & 26 \\ & 29 \end{aligned}$ | $\begin{aligned} & 35 \\ & 40 \end{aligned}$ | $\Omega$ |
| $\mathrm{r}_{\mathrm{DS} \text { (on) }}$ Flatness ${ }^{\text {d }}$ | ${ }^{\text {r DS(on) }}$ <br> Flatness | $\mathrm{V}+=2.5 \mathrm{~V}$ | Room |  | 10 |  |  |
| Switch Off <br> Leakage Current ${ }^{\dagger}$ | $\mathrm{I}_{\text {(foff) }}$ | $\mathrm{V}+=2.75 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=0.5 \mathrm{~V} / 1.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=1.5 \mathrm{~V} / 0.5 \mathrm{~V}$ | $\begin{gathered} \text { Room } \\ \text { Full }^{\text {d }} \end{gathered}$ | $\begin{aligned} & -250 \\ & -3.0 \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 3.0 \end{aligned}$ | $\begin{aligned} & \mathrm{pA} \\ & \mathrm{nA} \end{aligned}$ |
|  | $\mathrm{I}_{\mathrm{D} \text { (off) }}$ |  | Room Full ${ }^{\text {d }}$ | $\begin{aligned} & \hline-250 \\ & -3.0 \end{aligned}$ |  | $\begin{aligned} & 250 \\ & 3.0 \end{aligned}$ | pA |
| Channel-On Leakage Current ${ }^{\dagger}$ | $I_{\text {(on) }}$ | $\mathrm{V}+=2.75 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}=0.5 \mathrm{~V} / 1.5 \mathrm{~V}$ | $\begin{aligned} & \text { Room } \\ & \text { Full }^{\text {d }} \end{aligned}$ | $\begin{aligned} & -250 \\ & -3.0 \end{aligned}$ |  | $\begin{gathered} 250 \\ 3.0 \end{gathered}$ | $\begin{aligned} & \mathrm{pA} \\ & \mathrm{nA} \end{aligned}$ |
| Digital Control |  |  |  |  |  |  |  |
| Input High Voltage | $\mathrm{V}_{\text {INH }}$ |  | Full | 2 |  |  |  |
| Input Low Voltage | $\mathrm{V}_{\text {INL }}$ |  | Full |  |  | 0.4 |  |
| Input Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {in }}$ |  | Full |  | 3 |  | pF |
| Input Current | $\mathrm{I}_{\text {INL }}$ or $\mathrm{I}_{\text {INH }}$ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}+$ | Full | -1 |  | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |
| Turn-On Time | ${ }_{\text {ton }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{D}} \text { or } \mathrm{V}_{\mathrm{S}}=1.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ \text { Figures } 1 \text { and } 2 \end{gathered}$ | Room Full |  | 16 | $\begin{aligned} & 40 \\ & 45 \end{aligned}$ | ns |
| Turn-Off Time | $\mathrm{t}_{\text {OFF }}$ |  | $\begin{aligned} & \text { Room } \\ & \text { Full } \end{aligned}$ |  | 7 | $\begin{aligned} & 23 \\ & 28 \end{aligned}$ |  |
| Break-Before-Make Time | $t_{d}$ |  | Room ${ }^{\text {d }}$ | 1 | 12 |  |  |
| Charge Injection ${ }^{\text {d }}$ | $\mathrm{Q}_{\text {INJ }}$ | $\begin{gathered} \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega, \\ \text { Figure } 3 \end{gathered}$ | Room |  | 5 | 10 | pC |
| Off-Isolation ${ }^{\text {d }}$ | OIRR | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$ | Room |  | -73 |  | dB |
| Crosstalk ${ }^{\text {d }}$ | $\mathrm{X}_{\text {TALK }}$ |  | Room |  | - 70 |  |  |
| Source-Off Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {S(off) }}$ | $\mathrm{V}_{\mathrm{IN}}=0$ or $\mathrm{V}+\mathrm{f}=1 \mathrm{MHz}$ | Room |  | 7 |  | pF |
| Channel-On Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\mathrm{D} \text { (on) }}$ |  | Room |  | 20 |  |  |
| Drain-to-Source Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {DS(off) }}$ |  | Room |  | 20 |  |  |
| Power Supply |  |  |  |  |  |  |  |
| Power Supply Range | V+ |  |  | 2.25 |  | 2.75 | V |
| Power Supply Current ${ }^{\text {d }}$ | ${ }^{\text {I }}$ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ |  |  | 0.01 | 1.0 | $\mu \mathrm{A}$ |
| Power Consumption | $\mathrm{P}_{\mathrm{C}}$ |  |  |  |  | 0.3 | $\mu \mathrm{W}$ |


| SPECIFICATIONS $\mathrm{V}+=3 \mathrm{~V}$ |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Test Conditions Unless Otherwise Specified$\begin{gathered} \mathrm{V}_{+}=3 \mathrm{~V}, \pm 10 \% \\ \mathrm{~V}_{\mathrm{IN}}=0.4 \text { or } 2.0 \mathrm{~V}^{\mathrm{e}} \end{gathered}$ | Temp ${ }^{\text {a }}$ | $\begin{gathered} \text { Limits } \\ -40 \text { to } 85^{\circ} \mathrm{C} \\ \hline \end{gathered}$ |  |  | Unit |
|  |  |  |  | Min ${ }^{\text {b }}$ | Typ ${ }^{\text {c }}$ | Max ${ }^{\text {b }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |
| Analog Signal Range ${ }^{\text {d }}$ | $\begin{gathered} \hline \mathrm{V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{NC}} \\ \mathrm{~V}_{\mathrm{COM}} \end{gathered}$ |  | Full | 0 |  | V+ | V |
| Drain-Source On-Resistance ${ }^{\text {d }}$ | $r_{\text {dS(on) }}$ | $\mathrm{V}+=2.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=1.5 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=10 \mathrm{~mA}$ | Room Full |  | $\begin{aligned} & 15 \\ & 19 \end{aligned}$ | $\begin{aligned} & 25 \\ & 30 \end{aligned}$ | $\Omega$ |
| $\mathrm{r}_{\text {DS(on) }}$ Flatness ${ }^{\text {d }}$ | $r_{\text {DS(on) }}$ Flatness | $V_{S}=0$ to $\mathrm{V}+\mathrm{I}_{\mathrm{S}}=10 \mathrm{~mA}$ | Room |  | 7.5 |  |  |
| Switch Off Leakage Current ${ }^{\text {f }}$ | $\mathrm{I}_{\text {S(off) }}$ | $\mathrm{V}+=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V} / 3 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=3 \mathrm{~V} / 1 \mathrm{~V}$ | Room Full | $\begin{aligned} & \hline-500 \\ & -4.0 \end{aligned}$ |  | $\begin{gathered} 500 \\ 4.0 \end{gathered}$ | $\begin{aligned} & \mathrm{pA} \\ & \mathrm{nA} \end{aligned}$ |
|  | $\mathrm{I}_{\mathrm{D} \text { (off) }}$ |  | Room Full | $\begin{aligned} & \hline-500 \\ & -4.0 \end{aligned}$ |  | $\begin{gathered} 500 \\ 4.0 \end{gathered}$ | $\begin{aligned} & \mathrm{pA} \\ & \mathrm{nA} \end{aligned}$ |
| Channel-On Leakage Current ${ }^{\dagger}$ | $I_{\text {d (on) }}$ | $\mathrm{V}+=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}=1 \mathrm{~V} / 3 \mathrm{~V}$ | Room Full | $\begin{aligned} & \hline-500 \\ & -4.0 \end{aligned}$ |  | $\begin{gathered} 500 \\ 4.0 \end{gathered}$ | $\begin{aligned} & \mathrm{pA} \\ & \mathrm{nA} \end{aligned}$ |
| Digital Control |  |  |  |  |  |  |  |
| Input High Voltage | $\mathrm{V}_{\text {INH }}$ |  | Full | 2 |  |  | V |
| Input Low Voltage | $\mathrm{V}_{\text {INL }}$ |  | Full |  |  | 0.8 |  |
| Input Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {in }}$ |  | Full |  | 3 |  | pF |
| Input Current | $\mathrm{I}_{\text {INL }}$ or $\mathrm{I}_{\text {INH }}$ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ | Full | -1 |  | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |
| Turn-On Time ${ }^{\text {d }}$ | $\mathrm{t}_{\mathrm{ON}}$ | $V_{D} \text { or } V_{S}=2.0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> Figures1 and 2 | Room Full |  | 12 | $\begin{aligned} & 15 \\ & 20 \\ & \hline \end{aligned}$ | ns |
| Turn-Off Time ${ }^{\text {d }}$ | $\mathrm{t}_{\text {OFF }}$ |  | Room Full |  | 6 | $\begin{gathered} \hline 8 \\ 10 \end{gathered}$ |  |
| Break-Before-Make Time ${ }^{\text {d }}$ | $\mathrm{t}_{\mathrm{d}}$ |  | Room | 1 | 7 |  |  |
| Charge Injection ${ }^{\text {d }}$ | $\mathrm{Q}_{\text {INJ }}$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega,$ <br> Figure 3 | Room |  | 5 | 10 | pC |
| Off-Isolation ${ }^{\text {d }}$ | OIRR | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$ | Room |  | -73 |  | dB |
| Crosstalk ${ }^{\text {d }}$ | $\mathrm{X}_{\text {TALK }}$ |  | Room |  | - 70 |  |  |
| Source-Off Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {S(off) }}$ | $\mathrm{V}_{\mathrm{IN}}=0$ or $\mathrm{V}+\mathrm{f}=1 \mathrm{MHz}$ | Room |  | 7 |  | pF |
| Channel-On Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {(on) }}$ |  | Room |  | 20 |  |  |
| Drain-to-Source Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {DS(off) }}$ |  | Room |  | 20 |  |  |
| Power Supply |  |  |  |  |  |  |  |
| Power Supply Range | V+ |  |  | 2.7 |  | 3.3 | V |
| Power Supply Current | I+ | $\mathrm{V}_{\mathrm{IN}}=0 \text { or } \mathrm{V}_{+}$ |  |  | 0.01 | 1.0 | $\mu \mathrm{A}$ |
| Power Consumption | $\mathrm{P}_{\mathrm{C}}$ |  |  |  |  | 0.4 | $\mu \mathrm{W}$ |

## Vishay Siliconix

| SPECIFICATIONS $\mathrm{V}+=5 \mathrm{~V}$ |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Test Conditions Unless Otherwise Specified$\begin{gathered} \mathrm{V}+=5 \mathrm{~V}, \pm 10 \% \\ \mathrm{~V}_{\mathrm{IN}}=0.8 \text { or } 2.4 \mathrm{~V}^{\mathrm{e}} \end{gathered}$ | Temp ${ }^{\text {a }}$ | $\begin{gathered} \text { Limits } \\ -40 \text { to } 85^{\circ} \mathrm{C} \end{gathered}$ |  |  | Unit |
|  |  |  |  | Min ${ }^{\text {b }}$ | Typ ${ }^{\text {c }}$ | Max ${ }^{\text {b }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |
| Analog Signal Range ${ }^{\text {d }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{NC}} \\ \mathrm{~V}_{\mathrm{COM}} \end{gathered}$ |  | Full | 0 |  | V+ | V |
| Drain-Source On-Resistance | ${ }^{\text {d }}$ S(on) | $\mathrm{V}+=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=10 \mathrm{~mA}$ | Room Full |  | $\begin{gathered} \hline 7 \\ 10 \\ \hline \end{gathered}$ | $\begin{aligned} & 12 \\ & 16 \end{aligned}$ | $\Omega$ |
| $\mathrm{r}_{\text {DS(on) }}$ Flatness $^{\text {d }}$ | ${ }^{\mathrm{r}_{\mathrm{DS}}(o n)}$ Flatness | $\mathrm{V}+=2.5 \mathrm{~V}$ | Room |  | 2 |  |  |
| Switch Off <br> Leakage Current | $\mathrm{I}_{\mathrm{S} \text { (off) }}$ | $\mathrm{V}+=5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V} / 4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=4.5 \mathrm{~V} / 1 \mathrm{~V}$ | Room Full | $\begin{array}{r} -1.0 \\ -4.0 \end{array}$ |  | $\begin{aligned} & 1.0 \\ & 4.0 \end{aligned}$ | nA |
|  | $I_{\text {(off) }}$ |  | Room Full | $\begin{aligned} & -1.0 \\ & -4.0 \end{aligned}$ |  | $\begin{aligned} & 1.0 \\ & 4.0 \end{aligned}$ |  |
| Channel-On Leakage Current | $I_{\text {(on) }}$ | $\mathrm{V}+=5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}=1 \mathrm{~V} / 4.5 \mathrm{~V}$ | Room Full | $\begin{aligned} & -1.0 \\ & -3.0 \end{aligned}$ |  | $\begin{aligned} & 1.0 \\ & 4.5 \end{aligned}$ |  |
| Digital Control |  |  |  |  |  |  |  |
| Input High Voltage | $\mathrm{V}_{\text {INH }}$ |  | Full | 2.4 |  |  | V |
| Input Low Voltage | $\mathrm{V}_{\text {INL }}$ |  | Full |  |  | 0.8 |  |
| Input Capacitance | $\mathrm{C}_{\text {in }}$ |  | Full |  | 3 |  | pF |
| Input Current | $\mathrm{I}_{\mathrm{INL}}$ or $\mathrm{I}_{\mathrm{INH}}$ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ | Full | -1 |  | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |
| Turn-On Time ${ }^{\text {d }}$ | $\mathrm{t}_{\mathrm{ON}}$ | $V_{D} \text { or } V_{S}=3 V, R_{L}=300 \Omega, C_{L}=35 \mathrm{pF}$ <br> Figure 1 and 2 | Room Full |  | 9 | $\begin{aligned} & 11 \\ & 15 \end{aligned}$ | ns |
| Turn-Off Time ${ }^{\text {d }}$ | toff |  | Room Full |  | 5 | $\begin{aligned} & \hline 7 \\ & 9 \end{aligned}$ |  |
| Break-Before-Make Time ${ }^{\text {d }}$ | $\mathrm{t}_{\mathrm{d}}$ |  | Room | 1 | 4 |  |  |
| Charge Injection ${ }^{\text {d }}$ | $\mathrm{Q}_{\text {INJ }}$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega,$ <br> Figure 3 | Room |  | 5 | 10 | pC |
| Off-Isolation ${ }^{\text {d }}$ | OIRR | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$ | Room |  | -73 |  | dB |
| Crosstalk ${ }^{\text {d }}$ | $\mathrm{X}_{\text {TALK }}$ |  | Room |  | -70 |  |  |
| Source-Off Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {S(off) }}$ | $\mathrm{V}_{\mathrm{IN}}=0$ or $\mathrm{V}+, \mathrm{f}=1 \mathrm{MHz}$ | Room |  | 7 |  | pF |
| Channel-On Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\mathrm{D} \text { (on) }}$ |  | Room |  | 20 |  |  |
| Drain-to-Source Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\text {DS(off) }}$ |  | Room |  | 20 |  |  |
| Power Supply |  |  |  |  |  |  |  |
| Power Supply Range | V+ |  |  | 4.5 |  | 5.5 | V |
| Power Supply Current | I+ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ |  |  | 0.01 | 1.0 | $\mu \mathrm{A}$ |
| Power Consumption | $\mathrm{P}_{\mathrm{C}}$ |  |  |  |  | 0.6 | $\mu \mathrm{W}$ |

Notes:
a. Room $=25^{\circ} \mathrm{C}$, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, nor subjected to production test.
e. $\mathrm{V}_{\mathrm{IN}}=$ input voltage to perform proper function.
f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DG9411

TYPICAL CHARACTERISTICS $25^{\circ} \mathrm{C}$, unless otherwise noted


Vishay Siliconix
TYPICAL CHARACTERISTICS $25^{\circ} \mathrm{C}$, unless otherwise noted



Charge Injection vs. Analog Voltage

## TEST CIRCUITS




Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time


Figure 2. Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

## TEST CIRCUITS



Figure 4. Off-Isolation


Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71347.

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[^0]:    * Pb containing terminations are not RoHS compliant, exemptions may apply.

